



# P-Channel 40-V (D-S) MOSFET

PRODUCT SUMMARY					
V <sub>DS</sub> (V)	$R_{DS(on)}\left(\Omega\right)$	I <sub>D</sub> (A) <sup>b</sup>			
- 40	0.082 at V <sub>GS</sub> = - 10 V	- 3.0			
- 40	0.130 at V <sub>GS</sub> = - 4.5 V	- 2.4			

#### **FEATURES**

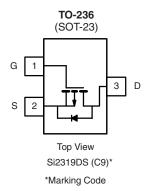
- Halogen-free According to IEC 61249-2-21 Available
- TrenchFET® Power MOSFET

# Pb-free RoHS

#### COMPLIANT HALOGEN FREE

## **APPLICATIONS**

· Load Switch



Ordering Information: Si2319DS-T1-E3 (Lead (Pb)-free)

Si2319DS-T1-GE3 (Lead (Pb)-free and Halogen-free)

Parameter		Symbol	5 s	Steady State	Unit
Drain-Source Voltage		V <sub>DS</sub>	- 40		V
Gate-Source Voltage		V <sub>GS</sub>	± 20		
Continues Projection Comment (T. 150.00)h	T <sub>A</sub> = 25 °C	- I <sub>D</sub>	- 3.0	- 2.3	_
Continuous Drain Current (T <sub>J</sub> = 150 °C) <sup>b</sup>	T <sub>A</sub> = 70 °C		- 2.4	- 1.85	
Pulsed Drain Current <sup>a</sup>		I <sub>DM</sub>	- 12		Α
Continuous Source Current (Diode Conduction) <sup>b</sup>		I <sub>S</sub>	- 1.0	- 0.62	
Develop Diseise attend	T <sub>A</sub> = 25 °C	P <sub>D</sub>	1.25	0.75	W
Power Dissipation <sup>b</sup>	T <sub>A</sub> = 70 °C		0.8	0.48	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150		°C

THERMAL RESISTANCE RATINGS					
Parameter	Symbol	Typical	Maximum	Unit	
Maximum Junction-to-Ambient <sup>b</sup>	- R <sub>thJA</sub>	75	100		
Maximum Junction-to-Ambient <sup>c</sup>	' 'thJA	120	166	°C/W	
Maximum Junction-to-Foot (Drain)	R <sub>thJF</sub>	40	50		

#### Notes:

- a. Pulse width limited by maximum junction temperature.
- b. Surface mounted on FR4 board,  $t \le 5$  s.
- c. Surface Mounted on FR4 board.

For Spice model information via the worldwide web: <a href="www.vishay.com/www/product/spice.htm">www.vishay.com/www/product/spice.htm</a>.

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			Limits				
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static	•			•			
Drain-Source Breakdown Voltage	$V_{DS}$	$V_{GS} = 0 \text{ V}, I_D = -250 \mu\text{A}$	- 40			V	
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}$ , $I_D = -250 \mu A$	- 1		- 3.0	V	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA	
Zava Cata Valtaga Dvain Current	1	V <sub>DS</sub> = - 40 V, V <sub>GS</sub> = 0 V			- 1		
Zero Gate Voltage Drain Current	IDSS	$V_{DS}$ = - 40 V, $V_{GS}$ = 0 V, $T_{J}$ = 55 °C			- 10	μΑ	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \le -5 \text{ V}, V_{GS} = -10 \text{ V}$	- 6			Α	
		$V_{GS} = -10 \text{ V}, I_D = -3.0 \text{ A}$		0.065	0.082		
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS} = -4.5 \text{ V}, I_D = -2.4 \text{ A}$		0.100	0.130	Ω	
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	$V_{DS} = -5 \text{ V}, I_D = -3.0 \text{ A}$		7.0		S	
Diode Forward Voltage <sup>a</sup>	$V_{SD}$	I <sub>S</sub> = - 1.25 A, V <sub>GS</sub> = 0 V		- 0.8	- 1.2	V	
Dynamic <sup>b</sup>							
Total Gate Charge	$Q_g$	V 20 V V 40 V		11.3	17	nC	
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS} = -20 \text{ V}, V_{GS} = -10 \text{ V}$ $I_{D} \cong -3 \text{ A}$		1.7			
Gate-Drain Charge	$Q_{gd}$	1D = 20 V		3.3		1	
Input Capacitance	C <sub>iss</sub>			470		pF	
Output Capacitance	C <sub>oss</sub>	$V_{DS} = -20 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		85			
Reverse Transfer Capacitance	C <sub>rss</sub>			65			
Switching <sup>c</sup>							
Turn-On Time	t <sub>d(on)</sub>			7	15	- ns	
ium-On Time	t <sub>r</sub>	$V_{DD}$ = - 20 V, $R_L$ = 20 Ω $I_D \cong$ - 1.0 A, $V_{GEN}$ = - 4.5 V		15	25		
Turn Off Time	t <sub>d(off)</sub>	$R_{\rm g} = 6 \Omega$		25	40		
Turn-Off Time	t <sub>f</sub>			25	40		

### Notes:

- a. Pulse test: PW  $\leq$  300  $\mu$ s duty cycle  $\leq$  2 %.
- b. For design aid only, not subject to production testing.
- c. Switching time is essentially independent of operating temperature.

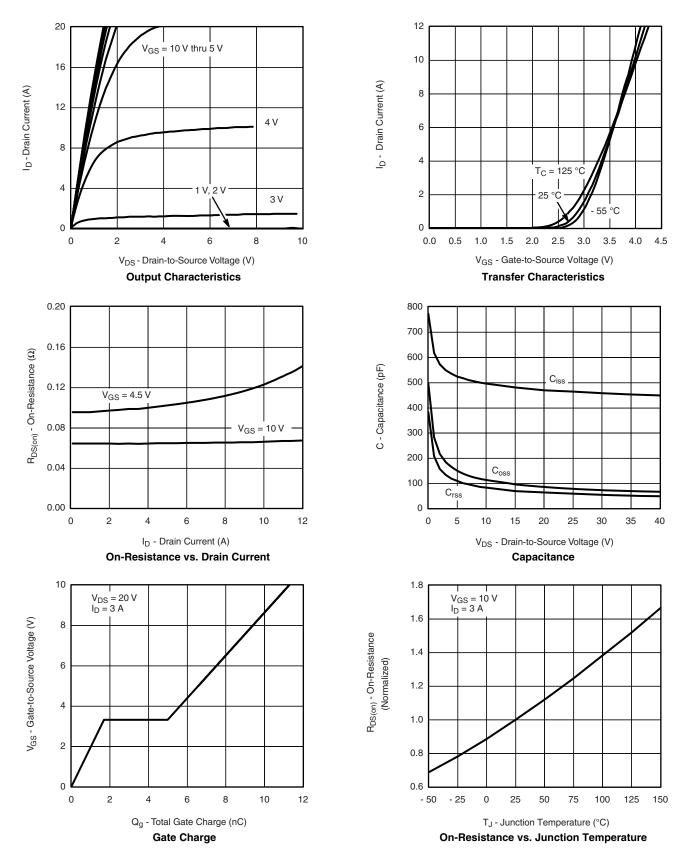
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.







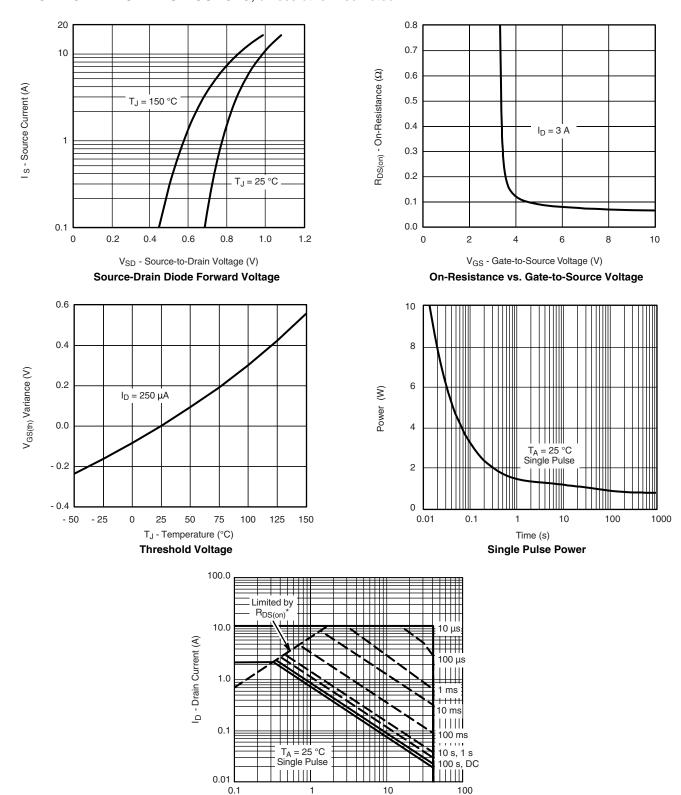
## TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



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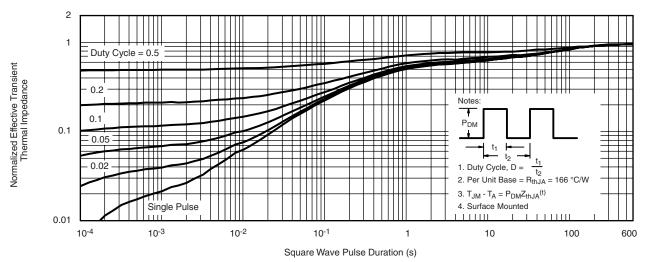


 $<sup>\</sup>rm V_{DS}$  - Drain-to-Source Voltage (V)  $^{\star}$  V  $_{GS}$  > minimum V  $_{GS}$  at which  $\rm R_{DS(on)}$  is specified

Safe Operating Area, Junction-to-Case



## TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

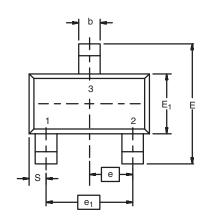


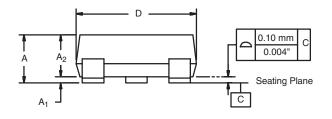
Normalized Thermal Transient Impedance, Junction-to-Ambient

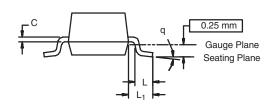
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## SOT-23 (TO-236): 3-LEAD







Dim	MILLIMETERS		INCHES		
	Min	Max	Min	Max	
Α	0.89	1.12	0.035	0.044	
A <sub>1</sub>	0.01	0.10	0.0004	0.004	
A <sub>2</sub>	0.88	1.02	0.0346	0.040	
b	0.35	0.50	0.014	0.020	
С	0.085	0.18	0.003	0.007	
D	2.80	3.04	0.110	0.120	
Е	2.10	2.64	0.083	0.104	
E <sub>1</sub>	1.20	1.40	0.047	0.055	
е	0.9	95 BSC 0.03		74 Ref	
e <sub>1</sub>	1.90 BSC		0.0748 Ref		
L	0.40	0.60	0.016	0.024	
L <sub>1</sub>	0.64 Ref		0.025 Ref		
S	0.50 Ref		0.020 Ref		
q	3°	8°	3°	8°	
FCN: S-03946-Rev K 09-	lul-01				

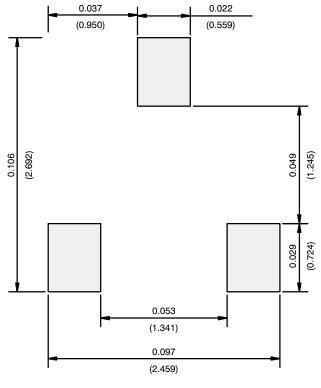
ECN: S-03946-Rev. K, 09-Jul-01

DWG: 5479

Document Number: 71196 www.vishay.com 09-Jul-01



## **RECOMMENDED MINIMUM PADS FOR SOT-23**



Recommended Minimum Pads Dimensions in Inches/(mm)

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APPLICATION NOTE



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